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	Applicant(s): Mizuhisa NIHEI, et al.	
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U.S. PATENT DOCUMENTS

Examiner Initial	Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
DS	AA	6,303,094	M. Kusunoki, et al.	10/16/01	—	—
DR	AB	6,278,231	T. Iwasaki, et al.	08/21/01	—	—
	AC					
	AD					

FOREIGN PATENT DOCUMENTS

	Document No.	Date	Country	Translation (Yes or No)
DS	AE	10-265208	10/06/98	Japan Yes-Abstract/Corresponds to USP 6303094/Discussed in the specification
DR	AF	2000-31462	01/28/00	Japan Yes-Abstract/Corresponds to USP 6278231/Discussed in the specification
	AG			

OTHER DOCUMENTS

DS	AH	P.P. Ruden, et al.; "Extrinsic Performance Limitations of AlGaN/GaN Heterostructure Field Effect Transistors"; <i>MRS Internet J. Nitride Semicond. Res.</i> ; 4S1, G6.35; 1999 (6 pages.)/Discussed in the specification
DR	AI	P. Kim, et al.; "Thermal Transport Measurements of Individual Multiwalled Nanotubes"; <i>Physical Review Letters</i> 87; 215502; November 19, 2001./Discussed in the specification
DR	AJ	M. Kusunoki, et al.; "A formation mechanism of carbon nanotube films on SiC(0001); <i>Applied Physics Letters</i> ; Vol. 77; Issue 4; July 24, 2000; p. 531./Discussed in the specification

Examiner

DOS

Date Considered

5/30/06